

SSM3J09FU

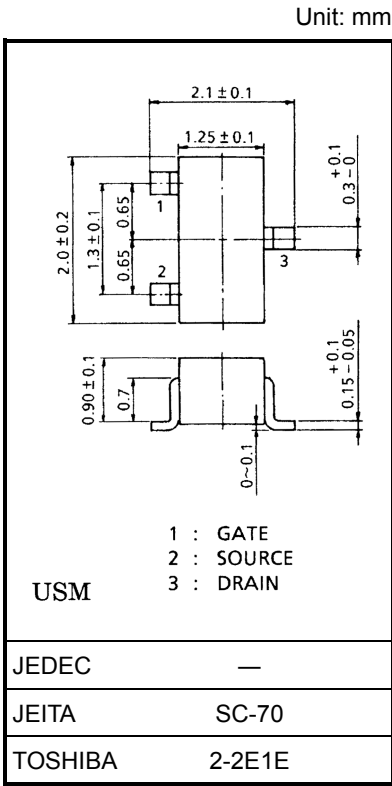
Management Switch
High Speed Switching Applications

- Small package
- Low on resistance: $R_{on} = 2.7\ \Omega$ (max) (@ $V_{GS} = -10\ V$)
 : $R_{on} = 4.2\ \Omega$ (max) (@ $V_{GS} = -4\ V$)

Maximum Ratings (Ta = 25°C)

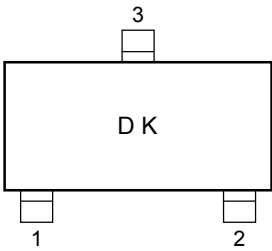
Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V_{DS}	-30	V
Gate-Source voltage		V_{GSS}	±20	V
Drain current	DC	I_D	-200	mA
	Pulse	I_{DP}	-400	
Drain power dissipation (Ta = 25°C)		P_D (Note1)	150	mW
Channel temperature		T_{ch}	150	°C
Storage temperature		T_{stg}	-55~150	°C

Note 1: Mounted on FR4 board
(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 0.6 mm² × 3) Figure 1.



Weight: 0.006 g (typ.)

Marking



Equivalent Circuit
(top view)

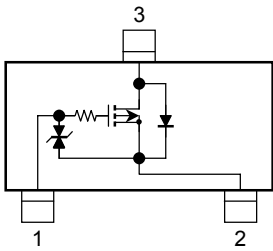
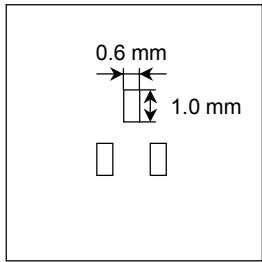


Figure 1: 25.4 mm × 25.4 mm × 1.6 t,
Cu Pad: 0.6 mm² × 3



Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

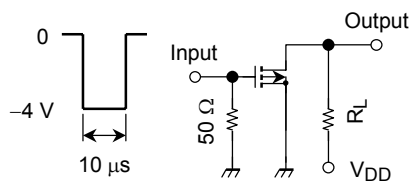
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	—	—	± 1	μA
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1 \text{ mA}, V_{GS} = 0$	-30	—	—	V
Drain cut-off current	I_{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0$	—	—	-1	μA
Gate threshold voltage	V_{th}	$V_{DS} = -5 \text{ V}, I_D = -0.1 \text{ mA}$	-1.1	—	-1.8	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -5 \text{ V}, I_D = -100 \text{ mA}$ (Note2)	115	—	—	mS
Drain-Source ON resistance	$R_{DS(ON)}$	$I_D = -100 \text{ mA}, V_{GS} = -10 \text{ V}$ (Note2)	—	2.1	2.7	Ω
		$I_D = -100 \text{ mA}, V_{GS} = -4 \text{ V}$ (Note2)	—	3.3	4.2	
		$I_D = -100 \text{ mA}, V_{GS} = -3.3 \text{ V}$ (Note2)	—	4.0	6.0	
Input capacitance	C_{iss}	$V_{DS} = -5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	22	—	pF
Reverse transfer capacitance	C_{rss}	$V_{DS} = -5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	5	—	pF
Output capacitance	C_{oss}	$V_{DS} = -5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	14	—	pF
Switching time	Turn-on time	t_{on}	$V_{DD} = -5 \text{ V}, I_D = -100 \text{ mA},$ $V_{GS} = 0 \sim -4 \text{ V}$		85	ns
	Turn-off time	t_{off}			85	ns

Note 2: Pulse test

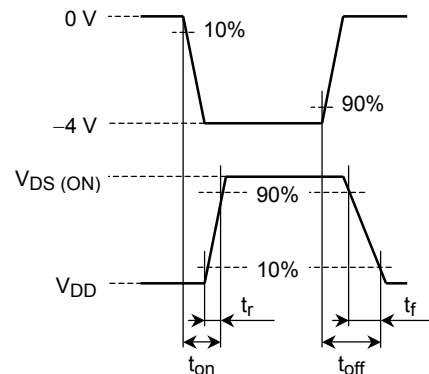
Switching Time Test Circuit

(a) Test circuit



$V_{DD} = -5 \text{ V}$
D.U. $\leq 1\%$
Input: $t_r, t_f < 5 \text{ ns}$
($Z_{out} = 50 \Omega$)
Common Source
Ta = 25°C

(b) V_{IN}



(c) V_{OUT}

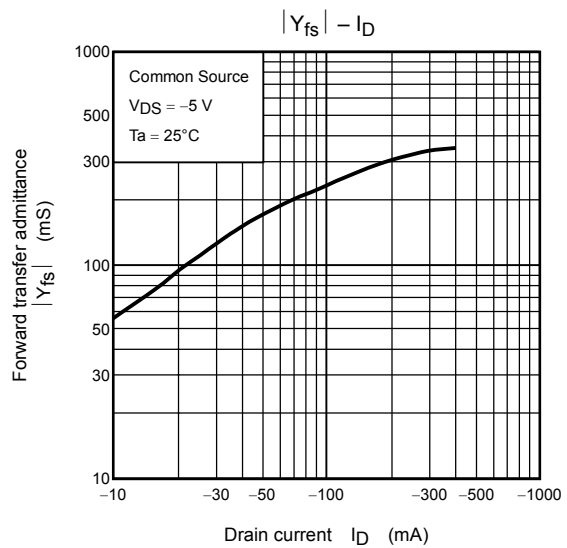
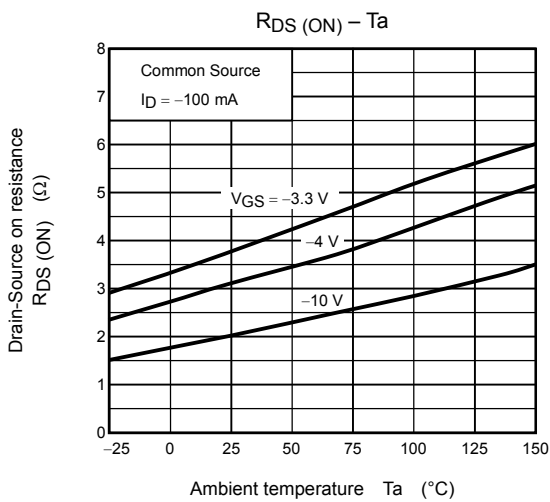
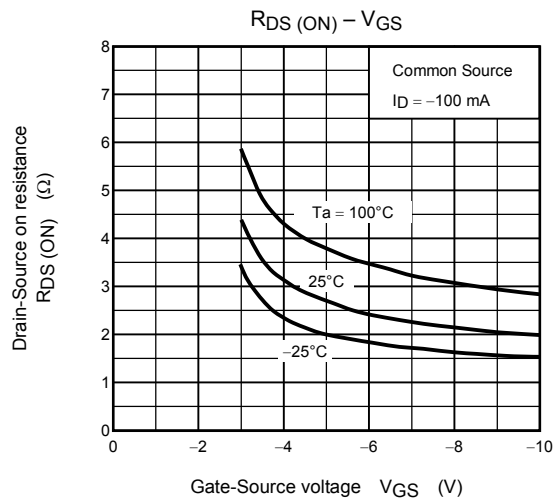
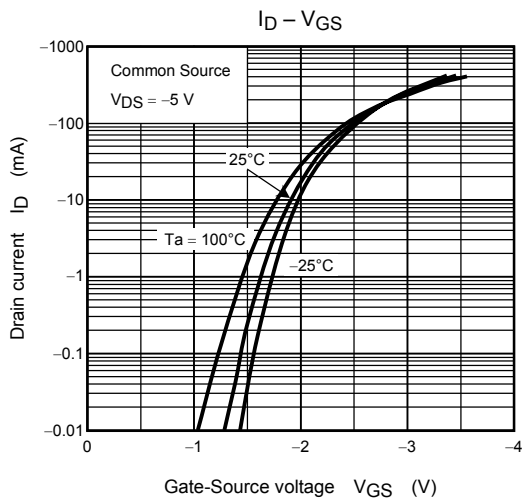
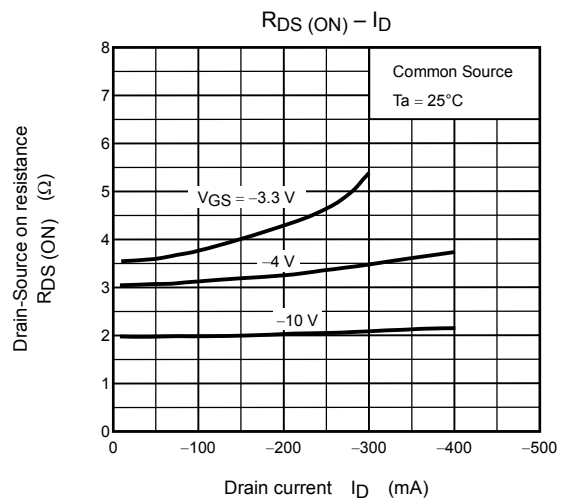
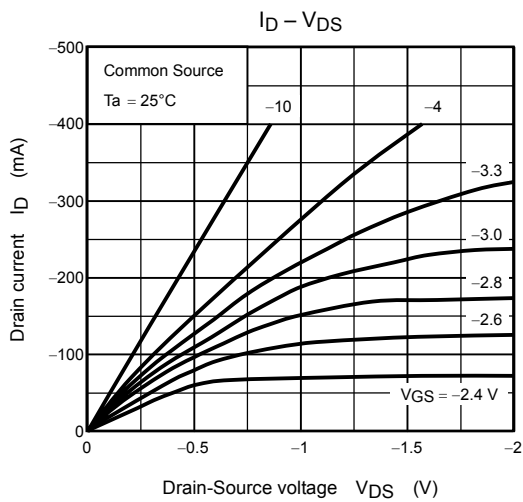
Precaution

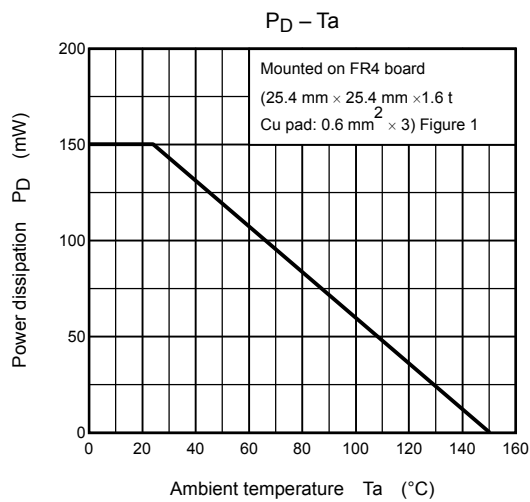
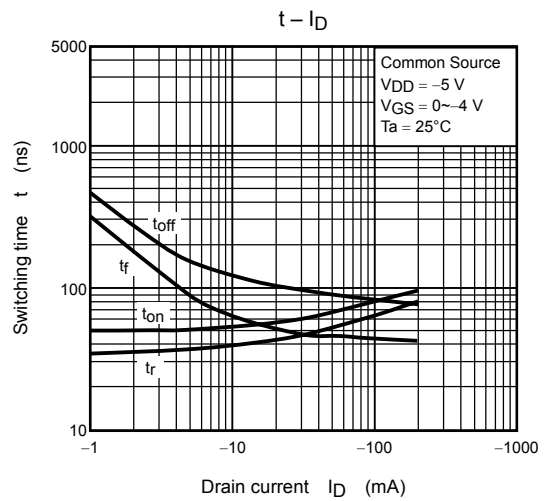
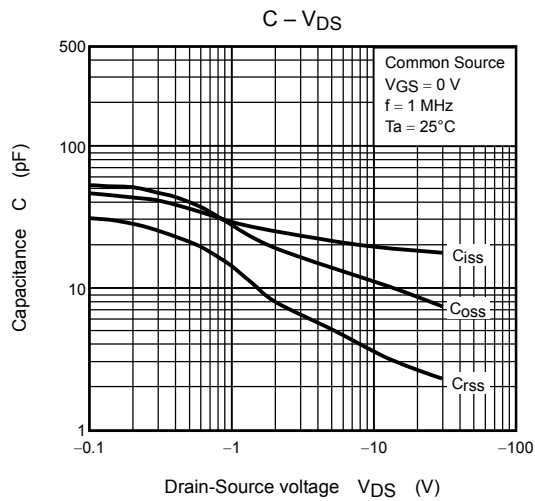
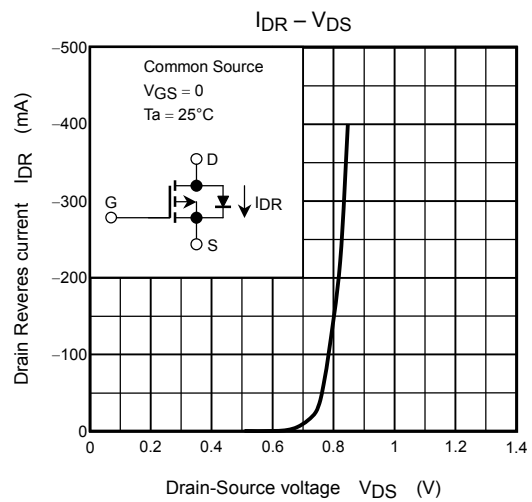
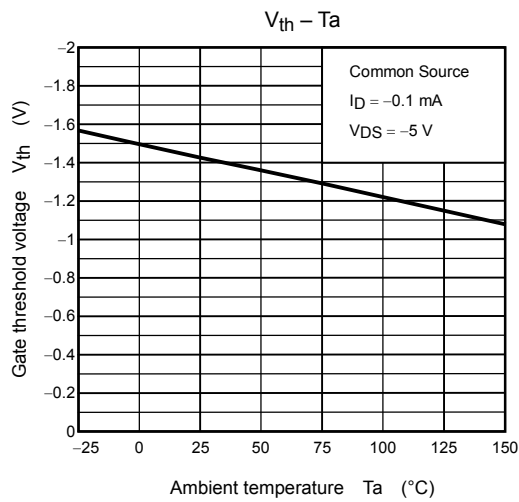
V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = -100 \mu\text{A}$ for this product. For normal switching operation, $V_{GS(ON)}$ requires higher voltage than V_{th} and $V_{GS(OFF)}$ requires lower voltage than V_{th} .

(relationship can be established as follows: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$)

Please take this into consideration for using the device.

V_{GS} recommended voltage of -4.0 V or higher to turn on this product.





RESTRICTIONS ON PRODUCT USE

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